

FEATURES

- Low noise
- Blueenhanced
- High shunt resistance
- High response

DESCRIPTION
The PDB-V115 is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for low noise photovoltaic applications. Packaged in a hermetic TO-5 metal can with a flat window.

## APPLICATIONS

- Instrumentation
- Oximeters
- Lasersensor
- Medical sensor

ABSOLUTE MAXIMUM RATING (TA=25 ${ }^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | MAX | UNITS |
| :---: | :--- | :---: | ---: | :---: |
| $\mathrm{V}_{\text {BR }}$ | Reverse Voltage |  | 75 | V |
| $\mathrm{~T}_{\text {STG }}$ | Storage Temperature | -55 | +150 | ${ }^{\circ} \mathrm{C}$ |
| T | Operating Temperature Range | -40 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{s}}$ | Soldering Temperature ${ }^{*}$ |  | +240 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{L}}$ | Light Current |  | 1.0 | mA |

*1/16 inch from case for 3 secs max

SPECTRALRESPONSE


ELECTRO-OPTICAL CHARACTERISTICS (TA $=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | CHARACTERISTIC | TESTCONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| Isc | Short Circuit Current | $\mathrm{H}=100 \mathrm{fc}, 2850 \mathrm{~K}$ | 40 | 60 |  | $\mu \mathrm{~A}$ |
| ID | Dark Current | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V}$ |  | 250 | 450 | pA |
| RsH | Shunt Resistance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ | 2 | 5 |  | $\mathrm{G} \Omega$ |
| TC RsH | RSH Temp. Coefficient | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ |  | -8 |  | $\% /{ }^{\circ} \mathrm{C}$ |
| C$\lrcorner$ | Junction Capacitance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=0 \mathrm{~V}^{* *}$ |  | 500 |  | pF |
| $\lambda_{\text {range }}$ | Spectral Application Range | Spot Scan | 350 |  | 1100 | nm |
| $\lambda_{\mathrm{p}}$ | Spectral Response - Peak | Spot Scan |  | 950 |  | nm |
| VBR | Breakdown Voltage | $\mathrm{I}=10 \mu \mathrm{~A}$ | 30 | 50 |  | V |
| NEP | Noise Equivalent Power | $\mathrm{VR}=10 \mathrm{mV} @$ Peak |  | $.5 \times 10^{-14}$ |  | $\mathrm{~W} / \sqrt{\mathrm{Hz}}$ |
| tr | Response Time | $\mathrm{RL}=1 \mathrm{~K} \Omega \mathrm{~V}_{\mathrm{R}}=0 \mathrm{~V}$ |  | 500 |  | nS |

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. **f $=1 \mathrm{MHz}$

